



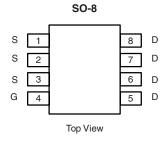
P-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A)		
	$0.042 \text{ at V}_{GS} = -10 \text{ V}$	- 5.7		
- 30	0.055 at V _{GS} = - 6 V	- 5.0		
	0.070 at V _{GS} = - 4.5 V	- 4.4		

FEATURES

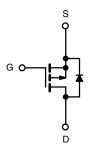
- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET[®] Power MOSFET
- Compliant to RoHS Directive 2002/95/EC





Ordering Information: Si9435BDY-T1-E3 (Lead (Pb)-free)

Si9435BDY-T1-GE3 (Lead (Pb)-free and Halogen-free)



P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS Parameter	- Д —	Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V _{DS}	- 30		
Gate-Source Voltage		V _{GS}	± 20		V
Ocaliana Paris Ocasa (T. 450.00)3	T _A = 25 °C	I _D	- 5.7	- 4.1	
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C		- 4.6	- 3.2	
Pulsed Drain Current		I _{DM}	- 30		Α
Continuous Source Current (Diode Conduction) ^a		I _S	- 2.3	- 1.1	
	T _A = 25 °C	- P _D	2.5	1.3	W
Maximum Power Dissipation ^a	T _A = 70 °C		1.6	0.8	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55	to 150	°C

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Manipulation to Application	t ≤ 10 s	R	40	50		
Maximum Junction-to-Ambient ^a	Steady State	R _{thJA}	70	95	°C/W	
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	24	30		

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

Si9435BDY

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SPECIFICATIONS $T_J = 25$ °	C, unless	otherwise noted					
Parameter	Symbol	Test Conditions	Min.	Typ. ^a	Max.	Unit	
Static							
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	- 1.0		- 3.0	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
Zoro Coto Voltago Drain Current	lana	$V_{DS} = -30 \text{ V}, V_{GS} = 0 \text{ V}$			- 1	μΑ	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = - 30 V, V _{GS} = 0 V, T _J = 70 °C			- 5		
On Otata Busin Commands	1-7	$V_{DS} \le -10 \text{ V}, V_{GS} = -10 \text{ V}$	- 20			^	
On-State Drain Current ^D	I _{D(on)}	$V_{DS} \le -5 \text{ V}, V_{GS} = -4.5 \text{ V}$	- 5			Α	
		$V_{GS} = -10 \text{ V}, I_D = -5.7 \text{ A}$		0.033	0.042	Ω	
Drain-Source On-State Resistance ^b	R _{DS(on)}	$V_{GS} = -6 \text{ V}, I_D = -5 \text{ A}$		0.043	0.055		
		V _{GS} = - 4.5 V, I _D = - 4.4 A		0.056	0.070		
Forward Transconductance ^b	9 _{fs}	$V_{DS} = -15 \text{ V}, I_{D} = -5.7 \text{ A}$		13		S	
Diode Forward Voltage ^b	V_{SD}	$I_S = -2.3 \text{ A}, V_{GS} = 0 \text{ V}$		- 0.8	- 1.1	V	
Dynamic ^a							
Total Gate Charge	Q_g			16	24		
Gate-Source Charge	Q _{gs}	$V_{DS} = -15 \text{ V}, V_{GS} = -10 \text{ V}, I_{D} = -3.5 \text{ A}$		2.3		nC	
Gate-Drain Charge	Q_{gd}			4.5			
Gate Resistance	R_g			8.8		Ω	
Turn-On Delay Time	t _{d(on)}			14	25		
Rise Time	t _r	V_{DD} = - 15 V, R_L = 15 Ω		14	25		
Turn-Off Delay Time	t _{d(off)}	$I_D\cong$ - 1 A, $V_{GEN}=$ - 10 V, $R_g=$ 6 Ω		42	70	ns	
Fall Time	t _f			30	50		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = - 1.2 A, dI/dt = 100 A/μs		30	60		

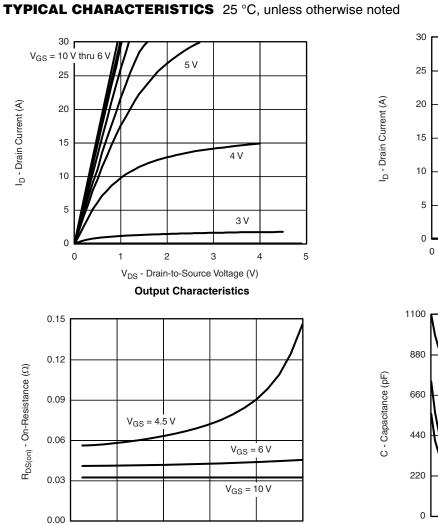
Notes:

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

a. Guaranteed by design, not subject to production testing.

b. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$





I_D - Drain Current (A)

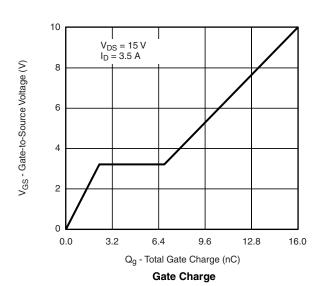
On-Resistance vs. Drain Current

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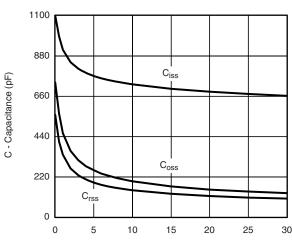
16

20

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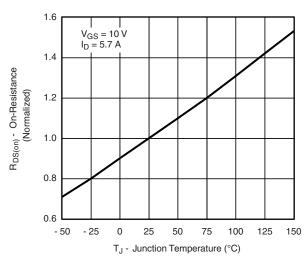


Transfer Characteristics



 $V_{\mbox{\footnotesize DS}}$ - Drain-to-Source Voltage (V)

Capacitance



On-Resistance vs. Junction Temperature

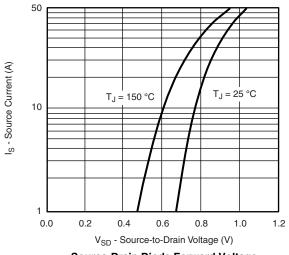
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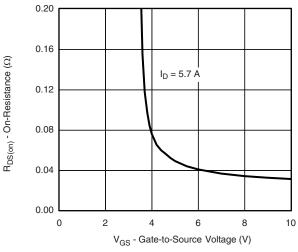
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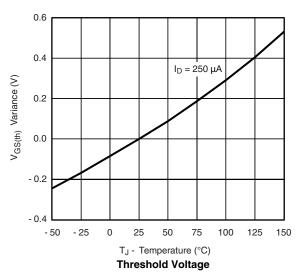
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

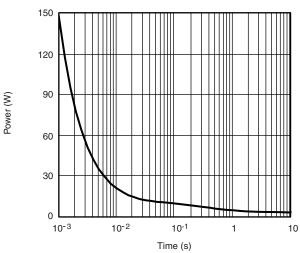




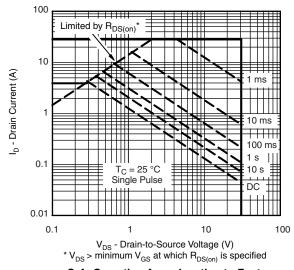
Source-Drain Diode Forward Voltage







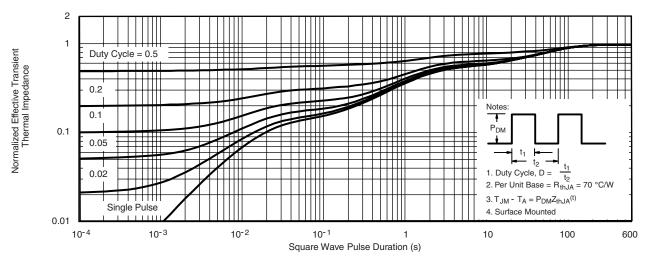
Single Pulse Power, Junction-to-Ambient



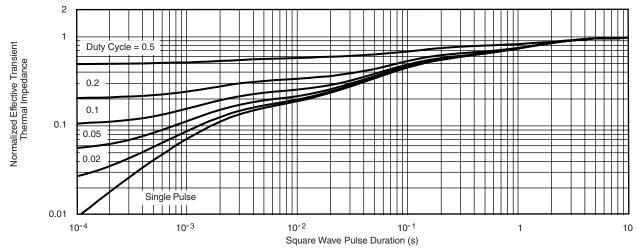
Safe Operating Area, Junction-to-Foot



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Foot

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?72245.



SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012







	MILLIM	IETERS	INCHES			
DIM	Min	Max	Min	Max		
Α	1.35	1.75	0.053	0.069		
A ₁	0.10	0.20	0.004	0.008		
В	0.35	0.51	0.014	0.020		
С	0.19	0.25	0.0075	0.010		
D	4.80	5.00	0.189	0.196		
E	3.80	4.00	0.150	0.157		
е	1.27	BSC	0.050 BSC			
Н	5.80	6.20	0.228	0.244		
h	0.25	0.50	0.010	0.020		
L	0.50	0.93	0.020	0.037		
q	0°	8°	0°	8°		
S	0.44	0.64	0.018	0.026		
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RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads Dimensions in Inches/(mm)

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